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LIST OF REFERENCES CITED BY APPLICANT

APPLICANT

Marc DELAUNAY, et al.

FILING DATE

April 25, 2005

GROUP

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
/RK/	AA	6,346,303	02/12/02	SHIH, Han-Chang et al.			
	AB						
	AC						
	AD						
	AE						
	AF						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO
/RK/	AG	1 129 990	09/05/01	EP	
/RK/	AH	98 00777	07/30/99	FR(Equivalent of US 6,319,372)	NO

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☐ Additional References sheet(s) attached

Examiner

/Robert Kunemund/

Date Considered 05/11/2007

*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.